

Hyunho Kim

List of Publications by Year in descending order

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Version: 2024-02-01

7
papers

92
citations

1937685
4
h-index

1872680
6
g-index

7
all docs

7
docs citations

7
times ranked

107
citing authors

| # | ARTICLE | IF | CITATIONS |
|---|--|-----|-----------|
| 1 | High-Performance Dual Gate Amorphous InGaZnO Thin Film Transistor With Top Gate to Drain Offset. IEEE Electron Device Letters, 2022, 43, 56-59. | 3.9 | 6 |
| 2 | Study on Residual Image in Low-Temperature Poly-Si Oxide TFT-Based OLED Display on Polyimide Substrate. IEEE Transactions on Electron Devices, 2022, 69, 4958-4961. | 3.0 | 2 |
| 3 | An 18.6- μ m-Pitch Gate Driver Using a-IGZO TFTs for Ultrahigh-Definition AR/VR Displays. IEEE Transactions on Electron Devices, 2020, 67, 4929-4933. | 3.0 | 14 |
| 4 | 39 th : Distinguished Student Paper: In π -Pixel Temperature Sensor for High π -Luminance Active π -Matrix Micro π -LED Display using LTPO TFTs. Digest of Technical Papers SID International Symposium, 2020, 51, 559-562. | 0.3 | 0 |
| 5 | 25 th : LTPO TFT Technology for Level Shifter Integrated Gate Driver in UHD 4K Displays. Digest of Technical Papers SID International Symposium, 2020, 51, 363-366. | 0.3 | 3 |
| 6 | In π -Pixel temperature sensor for high π -Luminance active matrix micro π -light π -emitting diode display using low π -temperature polycrystalline silicon and oxide thin π -film π -transistors. Journal of the Society for Information Display, 2020, 28, 528-534. | 2.1 | 9 |
| 7 | A High-Gain Inverter With Low-Temperature Poly-Si Oxide Thin-Film Transistors. IEEE Electron Device Letters, 2019, 40, 411-414. | 3.9 | 58 |